# 1. General description

Maximum Efficiency General Application (MEGA) Schottky barrier rectifier, encapsulated in a CFP15 (SOT1289) power and flat lead Surface-Mounted Device (SMD) plastic package.

#### 2. Features and benefits

- Average forward current: I<sub>F(AV)</sub> ≤ 10 A
- Reverse voltage: V<sub>R</sub> ≤ 100 V
- Low leakage current due to high Schottky barrier technology
- Low forward voltage
- High power capability due to clip-bonding technology and heat sink
- High temperature T<sub>i</sub> ≤ 175 °C
- Small and thin SMD power plastic package, typical height 0.78 mm
- AEC-Q101 qualified

# 3. Applications

- Low voltage rectification
- Automotive LED lighting
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection
- Low power consumption application

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; f = 20 kHz; $T_{amb} \le$ 150 °C; square wave	-	-	10	Α
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C	-	-	100	V
V <sub>F</sub>	forward voltage	$I_F$ = 10 A; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_j$ = 25 °C	-	770	850	mV
I <sub>R</sub>	reverse current	$V_R = 100 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.03;$ $T_j = 25 \text{ °C}$	-	0.2	1	μA





# 5. Pinning information

#### Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	Α	anode		K PA
2	Α	anode	3	aaa-009063
3	K	cathode	2 CFP15 (SOT1289)	

# 6. Ordering information

## Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
PMEG100V100ELPD	CFP15	plastic, thermal enhanced ultra thin SMD package; 3 leads; body: 5.8 x 4.3 x 0.78 mm	SOT1289		

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code
PMEG100V100ELPD	100V L10E

# 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>R</sub>	reverse voltage	T <sub>j</sub> = 25 °C		-	100	V
I <sub>F</sub>	forward current	T <sub>sp</sub> ≤ 145 °C; δ = 1		-	14	Α
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; f = 20 kHz; $T_{amb} \le$ 150 °C; square wave		-	10	А
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	170	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	1.66	W
			[2]	-	2.15	W
			[3]	-	3.75	W
Tj	junction temperature			-	175	°C
T <sub>amb</sub>	ambient temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-65	175	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.
- [3] Device mounted on a ceramic Printed-Circuit Board (PCB), Al<sub>2</sub>O<sub>3</sub>, standard footprint.

### 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance from junction to ambient	1	[1][2]	-	-	90	K/W	
		[1][3]	-	-	70	K/W	
		[1][4]	-	-	40	K/W	
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		[5]	-	-	3	K/W

- [1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P<sub>R</sub> are a significant part of the total power losses.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm<sup>2</sup>.
- [4] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.
- [5] Soldering point of cathode tab.

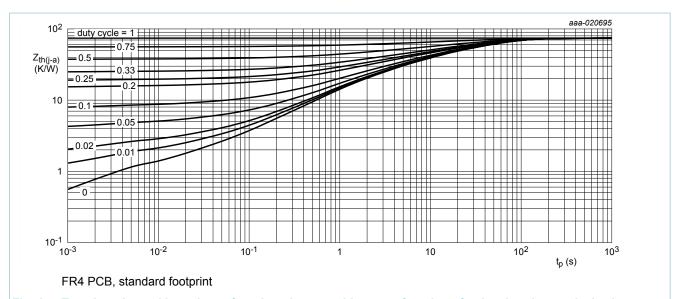


Fig. 1. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

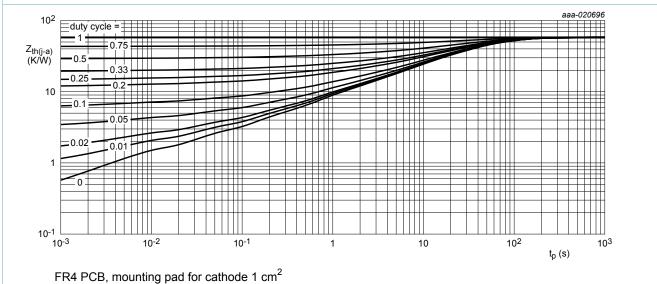
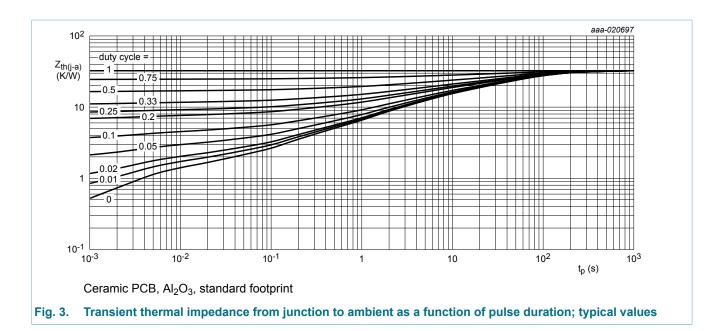


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

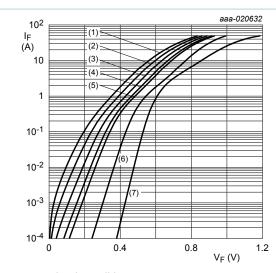


# 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)R</sub>	reverse breakdown voltage	$I_R$ = 1 mA; $t_p \le 1.2$ ms; $δ \le 0.12$ ; $T_j$ = 25 °C; pulsed	100	-	-	V
V <sub>F</sub> forw	forward voltage	$I_F$ = 0.1 A; $t_p$ ≤ 300 μs; δ ≤ 0.02 ; $T_j$ = 25 °C	-	440	-	mV
		$I_F$ = 1 A; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_j$ = 25 °C	-	545	650	mV
		$I_F$ = 2 A; $t_p$ ≤ 300 μs; δ ≤ 0.02 ; $T_j$ = 25 °C	-	610	710	mV
	$I_F$ = 4 A; $t_p$ ≤ 300 μs; δ ≤ 0.02 ; $T_j$ = 25 °C	-	685	-	mV	
		$I_F$ = 5 A; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_j$ = 25 °C	-	700	790	mV
		$I_F$ = 6 A; $t_p$ ≤ 300 μs; δ ≤ 0.02 ; $T_j$ = 25 °C	-	720	-	mV
		$I_F$ = 8 A; $t_p \le 300$ μs; $δ \le 0.02$ ; $T_j$ = 25 °C	-	745	-	mV
		$I_F$ = 10 A; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_j$ = 25 °C	-	770	850	mV
		$I_F = 10 \text{ A}; t_p \le 300  \mu\text{s}; \delta \le 0.02;$ $T_j = -40 ^{\circ}\text{C}$	-	870	960	mV

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		$I_F = 5 \text{ A}; t_p \le 300  \mu\text{s}; \delta \le 0.02;$ $T_j = 125 ^{\circ}\text{C}$	-	570	-	mV
		$I_F$ = 10 A; $t_p$ ≤ 300 μs; δ ≤ 0.02; $T_j$ = 125 °C	-	635	730	mV
I <sub>R</sub>	reverse current	$V_R = 60 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.03;$ $T_j = 25 \text{ °C}$	-	0.06	-	μA
		$V_R = 80 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.03;$ $T_j = 25 \text{ °C}$	-	0.09	-	μΑ
		$V_R = 100 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.03;$ $T_j = 25 ^{\circ}\text{C}$	-	0.2	1	μA
		$V_R = 100 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.03;$ $T_j = 125 \text{ °C}$	-	0.38	2.5	mA
		$V_R = 60 \text{ V}; t_p \le 3 \text{ ms}; \delta \le 0.03;$ $T_j = 150 \text{ °C}$	-	0.92	3.5	mA
C <sub>d</sub>	diode capacitance	V <sub>R</sub> = 1 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	365	-	pF
		V <sub>R</sub> = 4 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	215	-	pF
		V <sub>R</sub> = 10 V; f = 1 MHz; T <sub>j</sub> = 25 °C	-	135	-	pF
t <sub>rr</sub>	reverse recovery time	$I_F = 0.5 \text{ A}$ ; $I_R = 0.5 \text{ A}$ ; $I_{R(meas)} = 0.1 \text{ A}$ ; $I_{j} = 25 \text{ °C}$	-	14	-	ns
$V_{FRM}$	peak forward recovery voltage	$I_F = 0.5 \text{ A}; \text{ d}I_F/\text{d}t = 20 \text{ A/}\mu\text{s}; T_j = 25 ^{\circ}\text{C}$	-	555	-	mV



pulsed condition

(1)  $T_i = 175 \,^{\circ}C$ 

(2)  $T_i = 150 \, ^{\circ}C$ 

(3)  $T_i = 125 \, ^{\circ}C$ 

(4)  $T_i = 100 \, ^{\circ}C$ 

(5)  $T_i = 85^{\circ}C$ 

(6)  $T_i = 25 \,^{\circ}C$ 

 $(7) T_i = -40 °C$ 

Fig. 4. Forward current as a function of forward voltage; typical values

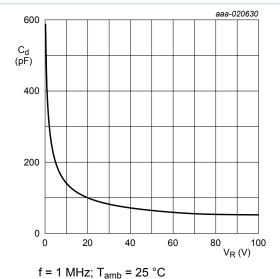
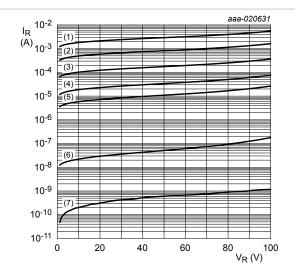


Fig. 6. Diode capacitance as a function of reverse voltage; typical values



pulsed condition

(1)  $T_i = 175 \,^{\circ}C$ 

(2)  $T_i = 150 \,^{\circ}\text{C}$ 

(3)  $T_i = 125 \,^{\circ}\text{C}$ 

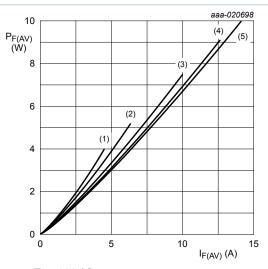
(4)  $T_i = 100 \, ^{\circ}C$ 

(5)  $T_i = 85 \, ^{\circ}C$ 

(6)  $T_i = 25 \,^{\circ}\text{C}$ 

 $(7) T_i = -40 ^{\circ}C$ 

Fig. 5. Reverse current as a function of reverse voltage; typical values



T<sub>i</sub> = 100 °C

 $(1) \delta = 0.1$ 

 $(2) \delta = 0.2$ 

 $(3) \delta = 0.5$ 

 $(4) \delta = 0.8$ 

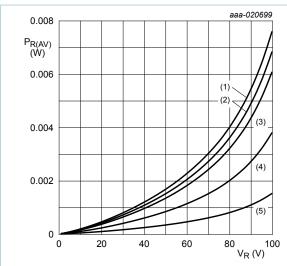
 $(5) \delta = 1$ 

Fig. 7. Average forward power dissipation as a function of average forward current; typical values

PMEG100V100ELPD

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T<sub>i</sub> = 100 °C

 $(1) \delta = 1$ 

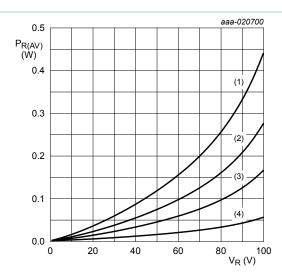
 $(2) \delta = 0.9$ 

 $(3) \delta = 0.8$ 

 $(4) \delta = 0.5$ 

 $(5) \delta = 0.2$ 

Fig. 8. Average reverse power dissipation as a function of reverse voltage; typical values



 $T_j = 175$  °C

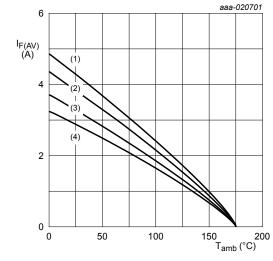
 $(1) \delta = 1$ 

 $(2) \delta = 0.5$ 

 $(3) \delta = 0.2$ 

 $(4) \delta = 0.1$ 

Fig. 9. Average reverse power dissipation as a function of reverse voltage; typical values



FR4 PCB, standard footprint

 $T_j = 175 \,{}^{\circ}\text{C}$ 

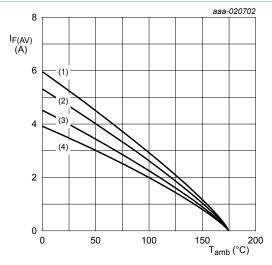
(1)  $\delta$  = 1; DC

(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta$  = 0.2; f = 20 kHz

(4)  $\delta$  = 0.1; f = 20 kHz

Fig. 10. Average forward current as a function of ambient temperature; typical values



FR4 PCB, mounting pad for cathode 1 cm<sup>2</sup>

T<sub>i</sub> = 175 °C

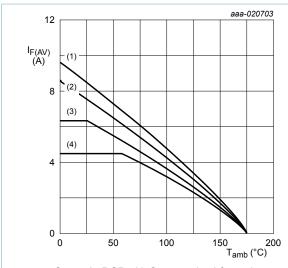
(1)  $\delta$  = 1; DC

(2)  $\delta = 0.5$ ; f = 20 kHz

(3)  $\delta = 0.2$ ; f = 20 kHz

(4)  $\delta = 0.1$ ; f = 20 kHz

Fig. 11. Average forward current as a function of ambient temperature; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

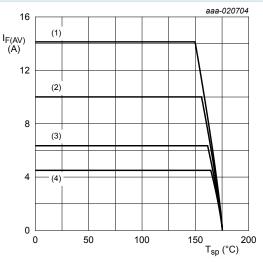
$$(1) \delta = 1 (DC)$$

(2)  $\delta = 0.5$ ; f = 20 kHz

(3) 
$$\delta = 0.2$$
;  $f = 20 \text{ kHz}$ 

(4)  $\delta$  = 0.1; f = 20 kHz

Fig. 12. Average forward current as a function of ambient temperature; typical values



(1) 
$$\delta = 1$$
 (DC)

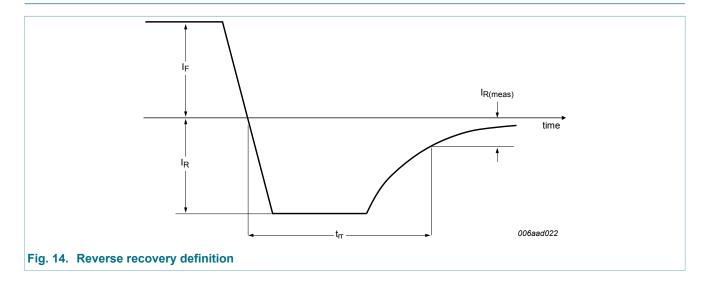
(2) 
$$\delta$$
 = 0.5; f = 20 kHz

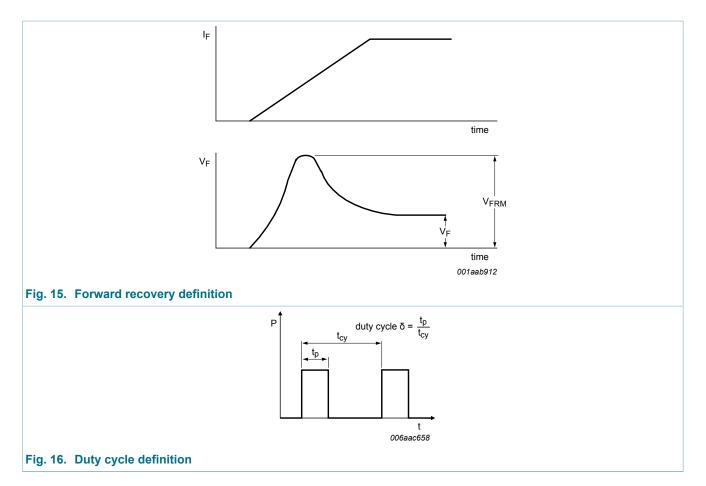
(3) 
$$\delta$$
 = 0.2; f = 20 kHz

(4) 
$$\delta$$
 = 0.1; f = 20 kHz

Fig. 13. Average forward current as a function of solder point temperature; typical values

# 11. Test information



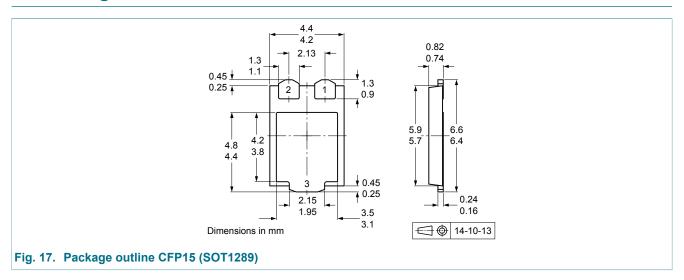


The current ratings for the typical waveforms are calculated according to the equations:  $I_{F(AV)} = I_M \times \delta$  with  $I_M$  defined as peak current,  $I_{RMS} = I_{F(AV)}$  at DC, and  $I_{RMS} = I_M \times \sqrt{\delta}$  with  $I_{RMS}$  defined as RMS current.

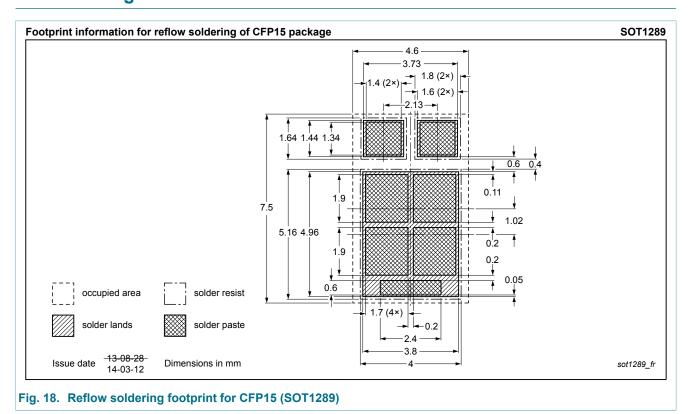
### 11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

# 12. Package outline



# 13. Soldering



# 14. Revision history

### Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMEG100V100ELPD v.2	20160203	Product data sheet	-	PMEG100V100ELPD v.1
Modifications:	Added Figure 1 to F	igure 3 and Figure 7 to F	igure 13.	
PMEG100V100ELPD v.1	20151117	Preliminary data sheet	-	-

# 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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